Electronic Supplementary Information (ESI)

Application of an inorganic sulfur-modified expanded graphite for

sodium storage at low temperature

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Experimental

Synthesis of S-EG

All chemicals utilized in this work were purchased from Aldrich and were of analytical grade without further purification. Initially, graphene oxide was prepared by the improved Hummers method.^[1] Then the black powder was heated highly to 850 °C at a heating-rate of 10 °C min⁻¹ and kept for 30 min in the atmosphere of Ar, followed by a careful collection of expanded graphite (EG). EG and commercial sublimed sulfur with a mass ratio of 1:1 were fully mixed by ball-milling in Ar and then were placed a vacuum tube furnace in Ar. The heating process was divided into three parts, including 155 °C for 1h, 300°C for 1h and 600 °C for 3h, respectively. Finally, expanded graphite expanded by few sulfur (S-EG) was carefully collected as a final sample.

Characterization

The phase analysis of the as-obtained products was characterized by a powder X-ray diffraction (XRD, Bruker D8 ADVANCE, Cu K α radiation, λ = 0.154 nm) at 40 kV, collected in the 20 range of 20~60° at a scanning speed of 5° min⁻¹. The morphologies and corresponding elemental mapping images were analyzed by scanning electron microscopy (SEM, Zeiss Ultra Plus, accelerating voltage: 15kV) and transmission electron microscopy (TEM, FEI Tecnai G2 F20, Accelerating voltage: 200kV). The element distribution was evaluated by X-ray photoelectron spectroscopy (XPS, Escalab 250 Xi) spectrum, using C 1s (Binding Energy: 284.6 eV) as a reference. N₂ adsorption/desorption isotherms were measured at liquid nitrogen temperature using ASAP 2460. Raman spectra were recorded on a Raman microprobe (HR800, HORIBA JY) with 632.8 nm laser excitation. Fourier transform infrared spectroscopy (FTIR) spectra were collected from a Cary 660 FTIR spectrometer (Agilent Technologies) with 32 scans at a resolution of 4 cm⁻¹. Thermogravimetric analysis (TGA) was performed under the Ar atmosphere with the heating rate of 5°C min⁻¹.

Electrochemical measurements

Galvanostatic charge/discharge performance were tested by CR2032-type cells assembled in a glove box under the Ar atmosphere with the vapor and the oxygen content strictly below 0.1ppm. The working electrodes were prepared by mixing the as-prepared anodes with super P and polyvinylidene fluoride (PVDF) at a respective weight ratio of 7:2:1 in N-methyl pyrrolidone (NMP) solvent. The coin cells were assembled with 1 M sodium perchlorate (NaClO₄) in a mixture of ethylene carbonate/dimethyl carbonate (EC/DMC) solution (1:1 in volume ratio) with 5wt% fluoroethylene carbonate (FEC) as the electrolyte, and the glass fiber membrane was the separator. Cyclic voltammetry (CV) and electrochemical impedance spectroscopy (EIS) measurements were performed on a CHI660E electrochemical station and a PARSTAT 2273 . electrochemical station, respectively. CV was collected at the different scan rates (0.1-2.0 mV s⁻¹) from 0 to 2.5 V and the testing range of EIS was a perturbation voltage of 5 mV in the frequency range between 100 kHz and 0.01 Hz at room temperatures. Galvanostatic The cyclic and rate performances were tested in the voltage range of 0-2.5 V on Land CT2001A battery test system.

Computational details

Galvanostatic intermittence titration technique (GITT) technique was also tested by the LAND system. Before the test, the batteries were charged/discharged at 0.2C for ten cycles to age the batteries. The batteries were performed for 20

min interlarding with a 60 min relaxing time at 0.2C, which was used to calculate the Na⁺ diffusion coefficient reflecting the kinetic behaviors of S-EG was calculated with the equation:

$$\frac{4}{\mathsf{D}_{\mathsf{GITT}}} = \frac{\pi t}{\pi t} \left(\frac{m_B V_m}{M_B S}\right)^2 \left(\frac{\Delta E_S}{\Delta E_t}\right)^2 \tag{3}$$

where D_{GITT} is the ion diffusion coefficient, t is the relaxing time of the current pulse, m_B is the mass of active materials, V_m is its molar volume (cm³ mol⁻¹), M_B is the molar mass (g mol⁻¹), S is the total contacting area of electrode with electrolyte, $\triangle E_s$ and $\triangle E_t$ signify the steady-state potential change by the current pulse and potential change during the constant current (V), which are eliminated with the iR drop.

The ${\rm D}_{\rm Na^+}$ value can be determined according to the following Equation:

$$D_{Na^+} = \frac{R^2 \times T^2}{2A^2 \times n^4 \times F^4 \times C_{Na^+}^2 \times \sigma^2}$$

where R is the gas constant, T is the absolute temperature, A is the electrode area, n is the number of transferred electrons, F is the Faraday constant, C_{Na}^+ is the Na⁺ concentration, and σ is the coefficient of Warburg impedance which is the slope of Z_{re} vs. $\omega^{1/2}$ plots.

Materials	Temperature	Current density	Specific	Ref.
	(°C)		capacity	
		(mA g ⁻¹)	(mAh g ⁻¹)	
Se/graphene	-5	243	346	[5]
Hard carbon	0	50	167	
Carbon nanosheets derived from corncob	0	50	132	
Carbon nanosphere derived from glucose	0	50	17	

Table S1 Comparison of low temperature properties of common carbon materials



Figure S1 EDS line-scanning result based on a TEM-HAADF and element distribution ratio.



Figure S2 The mass loss of S-EG and S based on thermogravimetric analysis (TGA) under Ar atmosphere.



Figure S3 Pore distribution of EG and S-EG.



Figure S4 Survey scan spectrum contained the peaks of carbon, sulfur and oxygen, the inset was the element ratio



Figure S5 XPS high-resolution spectra of O 1s for S-EG.



Figure S6 CV curves of the initial five cycles at 0.1 mV s⁻¹ at LT..



Figure S7 CV curves of EG and S-EG, respectively.



Figure S8 The 3rd charge and discharge profiles of EG and S-EG at 1.0C, respectively.



Figure S9 Nyquist plots of fresh cells employed EG and S-EG as anodes, respectively.



Figure S10 CV curves in the scan rate scope of 0.2 mV s $^{\text{-1}}$ and 2.0 mV s $^{\text{-1}}.$



Figure S11 Plots of Log *i vs.* Log *v* calculated from CV curves and their fitting lines.



Figure S12 Calculated data of the capacitive control under various scan rates.



Figure S13 A voltage-time profile during a GITT measurement at 0.2C



Figure S14 (a)Charge/discharge profiles of the initial three cycles at 0.1 C. (b) Cycle performance of S-EG and EG at 1C. (c) Charge/discharge profiles of the initial three cycles at 1 C (d) Rate performance of S-EG in the rate scope of 0.1 C and 2.0 C.



Figure S15 GITT curves and the calculate Na⁺ diffusion coefficients



Figure S16 A comparison of the properties of this work with previously reported anode materials for SIBs at RT/LT.^[2-7]



Figure S17 The fitting equivalent circuit.

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